

MFC8040

AUDIO PREAMPLIFIER

Advance Information

LOW NOISE AUDIO PREAMPLIFIER

... designed for high-gain, low-noise applications.

- Special Monolithic "State-of-the-Art" Process to Insure Low Noise – 1.0 μV (Typ)
- Can be Externally Equalized for NAB, RIAA
- Low Distortion – 0.1% (Typ) @ $A_V = 100$
- Large Dynamic Range – 7.0 V(rms) Out
- Low Output Impedance – 100 Ohms (Max)

LOW NOISE AUDIO PREAMPLIFIER

Silicon Monolithic
Functional Circuit

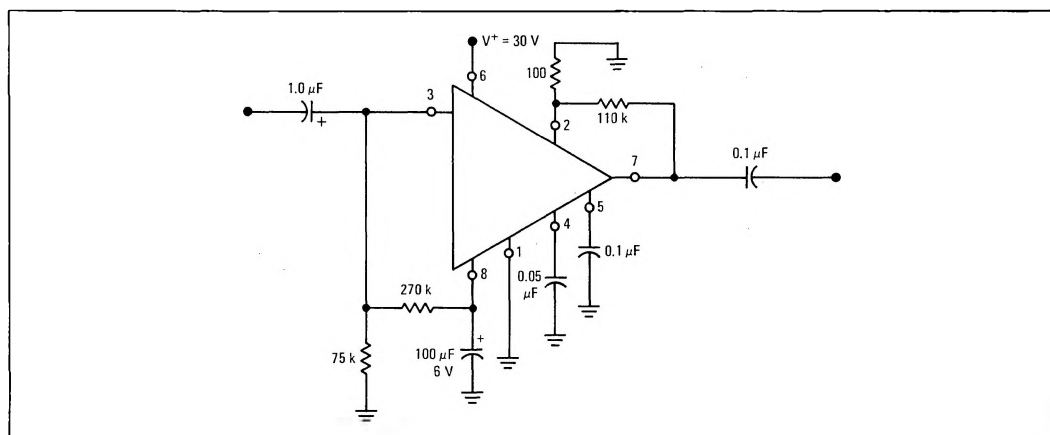


CASE 644A
PLASTIC PACKAGE

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Power Supply Voltage	V^+	33	Vdc
Power Dissipation @ $T_A = 25^\circ\text{C}$ (Package Limitation)	P_D	1.0	Watt
Derate above $T_A = 25^\circ\text{C}$	$1/\theta_{JA}$	10	mW/ $^\circ\text{C}$
Operating Temperature Range	T_A	-10 to +75	$^\circ\text{C}$

FIGURE 1 – TYPICAL WIDEBAND AMPLIFIER CIRCUIT ($A_V = 60\text{ dB}$)



See Packaging Information Section for outline dimensions.

MFC8040 (continued)

ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted)

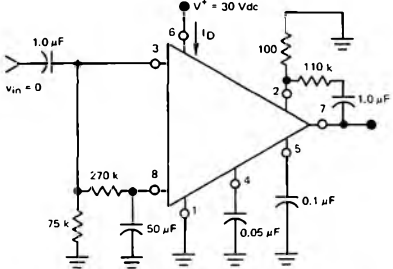
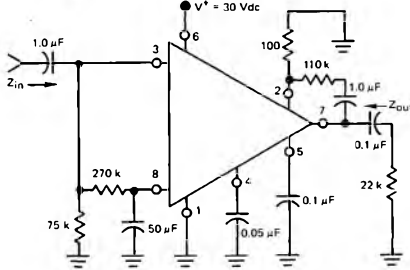
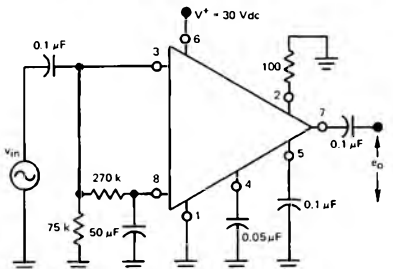
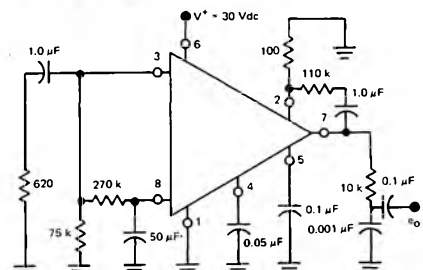
Circuit	Characteristic	Symbol	Min	Typ	Max	Unit
	Drain Current	ID	—	8.0	12	mA
	Total Harmonic Distortion (VO = 1.0 V, f = 1.0 kHz)	THD	—	<0.1	0.25	%
	Input Impedance	Zin	—	75	—	k ohms
	Output Impedance	Zout	—	100	—	ohms
	Open Loop Voltage Gain (VIN = 100 μV(rms) @ f = 1.0 kHz)	AVOL	80	—	—	dB
	Wideband Input Noise (-3.0 dB Bandwidth, 10 Hz to 16 kHz, AV = 60 dB @ 1.0 kHz, $e_n = \frac{e_o}{A_V}$)	en	—	1.0	3.0	μV (rms)

FIGURE 2 – CIRCUIT SCHEMATIC

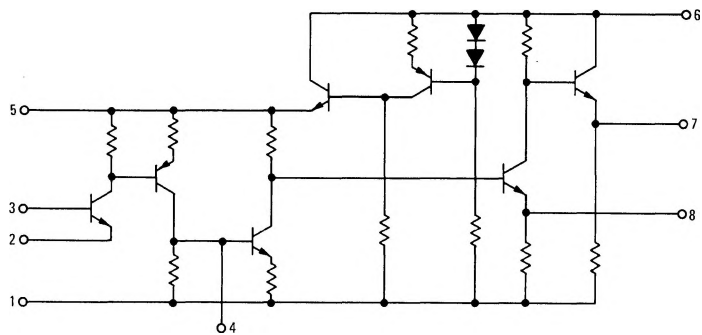


FIGURE 3 – INPUT NOISE

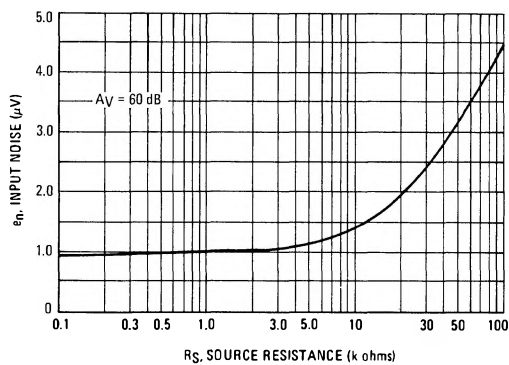


FIGURE 4 – OPEN LOOP TOTAL HARMONIC DISTORTION

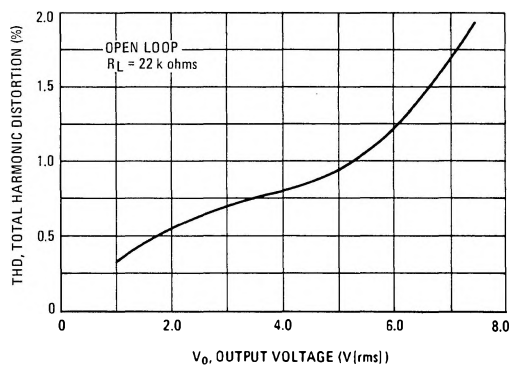


FIGURE 5 – AVAILABLE OUTPUT VOLTAGE

